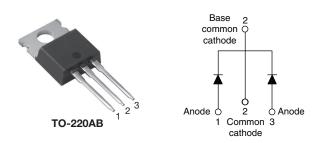
**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 2 x 8 A



www.vishay.com

PRODUCT SUMMARY								
Package	TO-220AB							
I <sub>F(AV)</sub>	2 x 8 A							
V <sub>R</sub>	60 V, 80 V, 100 V							
V <sub>F</sub> at I <sub>F</sub>	0.58 V							
I <sub>RM</sub> max.	7 mA at 125 °C							
T <sub>J</sub> max.	175 °C							
Diode variation	Common cathode							
E <sub>AS</sub>	7.5 mJ							

### **FEATURES**

- 175 °C T<sub>J</sub> operation
- · Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



RoHS

COMPLIANT

- HALOGEN · Guard ring for enhanced ruggedness and long FREE term reliability
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I <sub>F(AV)</sub>	Rectangular waveform	16	А							
V <sub>RRM</sub>		60 to 100	V							
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	А							
V <sub>F</sub>	8 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.58	V							
TJ	Range	- 55 to 175	°C							

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-16CTQ060HN3	VS-16CTQ080HN3	VS-16CTQ100HN3	UNITS
Maximum DC reverse voltage	V <sub>R</sub>				
Maximum working peak reverse voltage	V <sub>RWM</sub>	60	80	100	V

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	VALUES	UNITS						
Maximum average forward per leg		50 % duty cycle at $T_{a} = 1/8$ °	8	А					
See fig. 5 per device		$I_{F(AV)}$ 50 % duty cycle at T <sub>C</sub> = 148 °C, rectangular waveform							
Maximum peak one cycle non-repetitive surge current per leg	1	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated	850	A				
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	275					
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 0.50 A, L = 60 mH		7.50	mJ				
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to ze Frequency limited by T <sub>J</sub> maxim		0.50	А				

Revision: 05-Mar-14

Document Number: 94848

1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000

# VS-16CTQ...HN3 Series



www.vishay.com

# Vishay Semiconductors

ELECTRICAL SPECIFICATIO	DNS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS			
		8 A	T <sub>.1</sub> = 25 °C	0.72	v			
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	16 A	1j=25 0	0.88				
See fig. 1	VFM (")	8 A	T <sub>.1</sub> = 125 °C	0.58				
		16 A	1j = 125 C	0.69				
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = rated $V_{\rm B}$	0.55	mA			
See fig. 2	IRM (')	T <sub>J</sub> = 125 °C	$v_{\rm R} = rateu v_{\rm R}$	7.0				
Threshold voltage	V <sub>F(TO)</sub>			0.415	V			
Forward slope resistance	r <sub>t</sub>	ij = ij maximum	$T_J = T_J$ maximum		mΩ			
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range	500	pF				
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 m	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	Rated V <sub>R</sub>					

#### Note

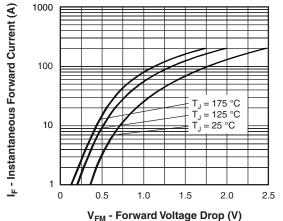
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

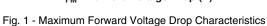
THERMAL - MECHANICAL SP	PECIFICA	TIONS			
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C	
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	3.25	°C/W	
Maximum thermal resistance junction to case per package	R <sub>thJC</sub>	Do operation	1.63	°C/ ¥¥	
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50		
Approximate weight			2	g	
Approximate weight			0.07	oz.	
Mounting to your			6 (5)	kgf∙cm	
Mounting torque maximum			12 (10)	(lbf ⋅ in)	
			16CTQ060		
Marking device		Case style TO-220AB	16CTQ080H		
			16CTQ100H		



## VS-16CTQ...HN3 Series

**Vishay Semiconductors** 







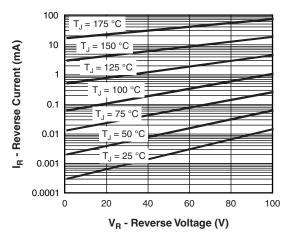


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

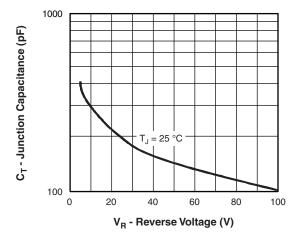


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

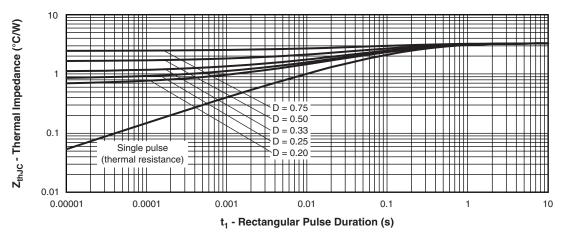
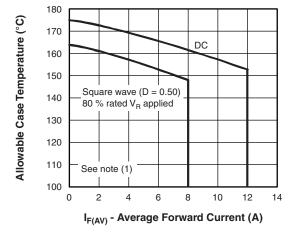
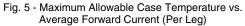


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

Revision: 05-Mar-14 3 Document Number: 94848 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>







**Vishay Semiconductors** 

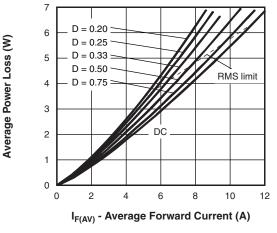


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

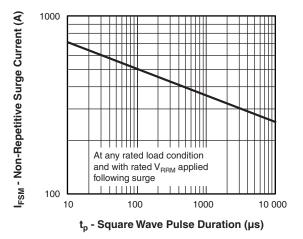


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \ \mathsf{applied} \end{array}$ 



## Vishay Semiconductors

#### **ORDERING INFORMATION TABLE**

Device code	VS-	16	С	т	Q	100	Н	N3
		(2)	(3)	(4)	(5)	(6)	(7)	(8)
	1	Viel	Sen	niconduc	tors pro	duct	0	0
	2 -		-	ng (16 =		auor		
	3 -			iguratior				
				on catho				
	4 -	Pac	kage					
		T =	TO-220	)		-		
	5 -	Sch	ottky "G	" series			060 = 6	
	6 -	Volt	age rati	ng —			080 = 8 100 = 1	
	7 -	. н=	AEC-Q	101 qua	lified	L		
	8 -	. Env	rironmei	ntal digit				
		• 1	13 = Hal	ogen-fre	e, RoH	S-comp	liant, ar	nd totall

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-16CTQ060HN3	50	1000	Antistatic plastic tube							
VS-16CTQ080HN3	50	1000	Antistatic plastic tube							
VS-16CTQ100HN3	50	1000	Antistatic plastic tube							

LINKS TO RELATED DOCUMENTS								
Dimensions www.vishay.com/doc?95222								
Part marking information TO-22	20AB -N3 www.vishay.com/doc?95028							
SPICE model	www.vishay.com/doc?95279							

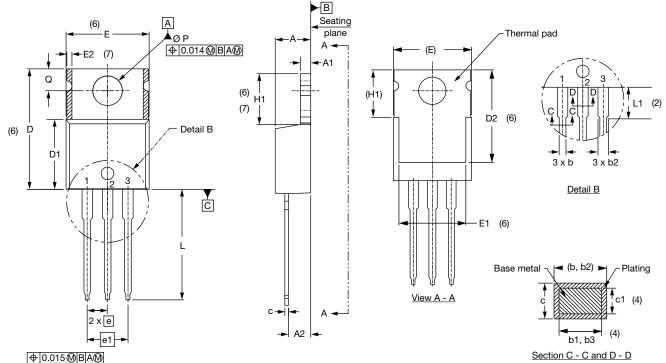
## **Outline Dimensions**



**Vishay Semiconductors** 

**TO-220AB** 

### **DIMENSIONS** in millimeters and inches



Lead tip

Conforms to JEDEC<sup>®</sup> outline TO-220AB

SYMBOL	MILLIMETERS		TERS INCHES		NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.25	4.65	0.167	0.183			D2	11.68	12.88	0.460	0.507	6
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.56	2.92	0.101	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			E2	-	0.76	-	0.030	7
b1	0.38	0.97	0.015	0.038	4		е	2.41	2.67	0.095	0.105	
b2	1.20	1.73	0.047	0.068			e1	4.88	5.28	0.192	0.208	
b3	1.14	1.73	0.045	0.068	4		H1	5.84	6.86	0.230	0.270	6, 7
с	0.36	0.61	0.014	0.024			L	13.52	14.02	0.532	0.552	
c1	0.36	0.56	0.014	0.022	4		L1	3.32	3.82	0.131	0.150	2
D	14.85	15.25	0.585	0.600	3		ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Dimension b1, b3 and c1 apply to base metal only

<sup>(5)</sup> Controlling dimensions: inches

<sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2 and E1

<sup>(7)</sup> Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed

(8) Outline conforms to JEDEC<sup>®</sup> TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Revision: 06-Mar-2020 1 Document Number: 95222 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.